VS-VSKD56.., VS-VSKE56.., VS-VSKJ56.., VS-VSKC56.. Series



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## AAP Gen 7 (TO-240AA) **Power Modules Standard Diodes, 60 A**



### ADD-A-PAK

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	60 A					
Туре	Modules - diode, high voltage					
Package	AAP Gen 7 (TO-240AA)					
Circuit configuration	Two diodes doubler circuit, two diodes common cathode, two diodes common anode, single diode					

## **MECHANICAL DESCRIPTION**

The AAP Gen 7 (TO-240AA), new generation of AAP module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

## **FEATURES**

#### High voltage

- Industrial standard package
- · Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **BENEFITS**

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- · High surge capability
- Easy mounting on heat sink

## **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
		60	A				
I <sub>F(AV)</sub>	T <sub>C</sub>	114	C°				
I <sub>F(RMS)</sub>		94					
	50 Hz	1300	А				
I <sub>FSM</sub>	60 Hz	1360					
l <sup>2</sup> t	50 Hz	8.44	kA <sup>2</sup> s				
1-1	60 Hz	7.68	KA-S				
l²√t		84.5	kA²√s				
V <sub>RRM</sub>	Range	400 to 1600	V				
T <sub>Stg</sub>		-40 to +150	°C				
TJ		-40 to +150	٥°				

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### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = 150 °C mA				
	04	400	500					
	06	600	700					
	08	800	900					
VS-VSK.56	10	1000	1100	10				
	12	1200	1300					
	14	1400	1500					
	16	1600	1700					

FORWARD CONDUCTION						
PARAMETER	SYMBOL		TEST CON	VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	180° conduction, half sine wave			60	A
at case temperature	'F(AV)		ction, nan sinc	wave	114	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>				94	
		t = 10 ms	No voltage		1300	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		1360	А
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		1090	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1140	
	l <sup>2</sup> t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	8.44	kA <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms	reapplied		7.68	
Maximum -t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		5.97	
		t = 8.3 ms	reapplied		5.43	
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	84.5	kA²√s
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	(I <sub>F(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum	0.74	v
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)})$	), $T_J = T_J$ maxir	num	0.86	v
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi$	3.94	mΩ	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)})$	<sub>)</sub> ), T <sub>J</sub> = T <sub>J</sub> maxir	3.43	1115.2	
Maximum forward voltage drop	V <sub>FM</sub>	$I_{FM} = \pi \times I_{F(x)}$	<sub>AV)</sub> , T <sub>J</sub> = 25 °C,	t <sub>p</sub> = 400 μs square wave	1.6	V

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse leakage current	I <sub>RRM</sub>	T <sub>J</sub> = 150 °C	10	mA
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V

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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	PARAMETER		TEST CONDITIONS	VALUES	UNITS			
Junction and storage temp	erature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C			
Maximum internal thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.33	°C/W			
Typical thermal resistance, case to heat sink per module		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1	0/11			
	to heatsink		A mounting compound is recommended and the	4				
Mounting torque ± 10 %	busbar		torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	3	Nm			
Approximate weight				75	g			
				2.7	oz.			
Case style			JEDEC®	AAP Gen 7	(TO-240AA)			

SINE HALF WAVE CONDUCTION RECTANGULAR WAVE CONDUCT						CONDUCTIO	Л				
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	<b>30</b> °	UNITS
VSK.56	0.115	0.136	0.173	0.236	0.346	0.09	0.145	0.185	0.243	0.349	°C/W

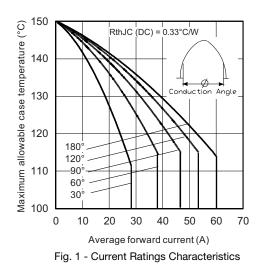
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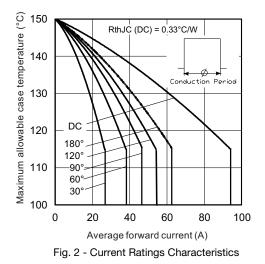
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Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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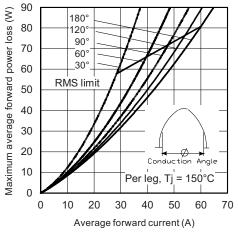


Fig. 3 - Forward Power Loss Characteristics

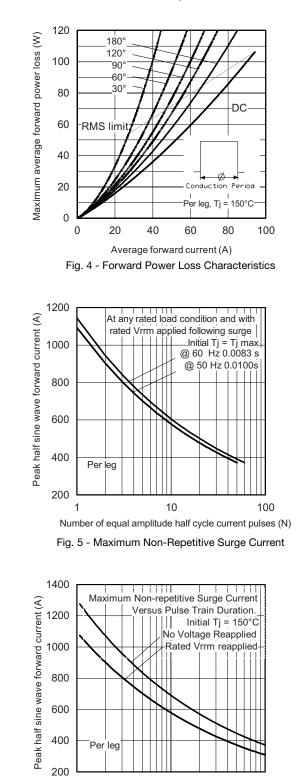


Fig. 6 - Maximum Non-Repetitive Surge Current

0.1

Pulse train duration (s)

0.01

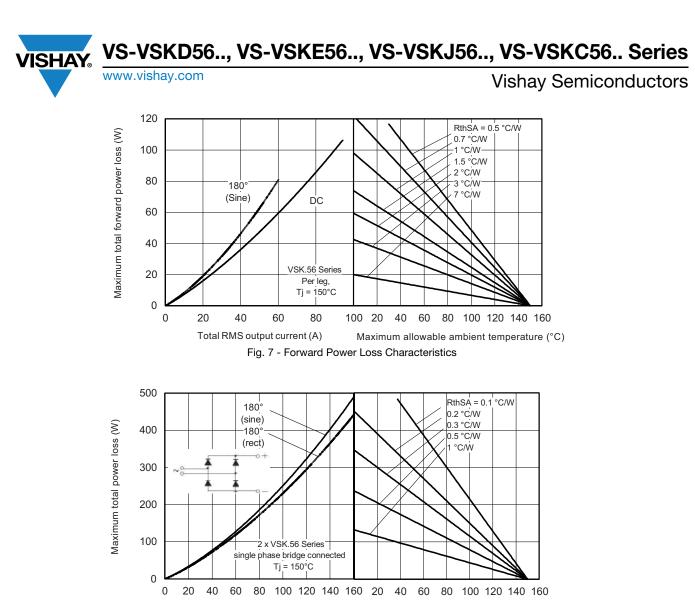
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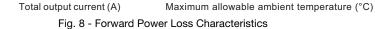
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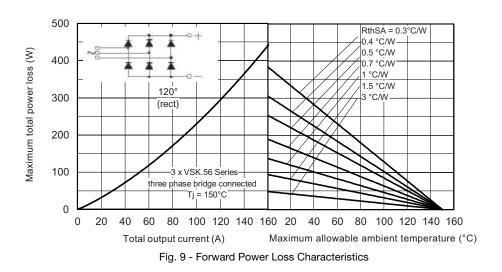
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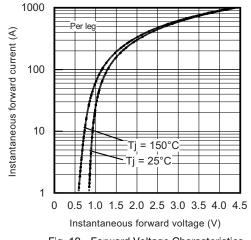


Fig. 10 - Forward Voltage Characteristics

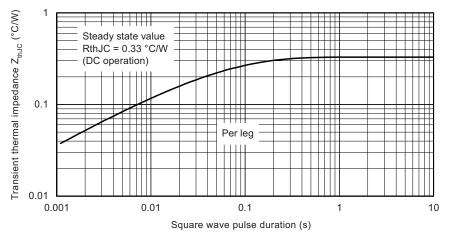
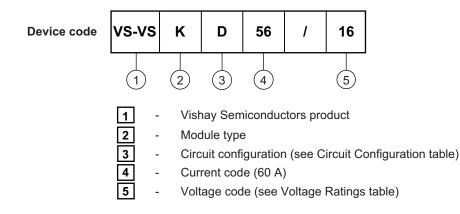


Fig. 11 - Thermal Impedance ZthJC Characteristics

### **ORDERING INFORMATION TABLE**



#### Note

To order the optional hardware go to <u>www.vishay.com/doc?95172</u>

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CIRCUIT CONFIGURATION						
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two diodes doubler circuit	D					
Two diodes common cathode	С					
Two diodes common anode	J					
Single diode	E					

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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## **ADD-A-PAK Generation VII - Diode**

### **DIMENSIONS** in millimeters (inches)





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25.330.1653.1 25.	.330.4753.1	25.330.5253.1	25.334.3253.1	25.334.3353.1	25.350.2053.0	25.352.4753.1	25.522.3253.0	<u>T483C</u> <u>T484C</u>
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